

# Radar Pulsed Power Transistor 90W, 3.1-3.5 GHz, 2µs Pulse, 10% Duty

## M/A-COM Products Released, 10 Aug 07

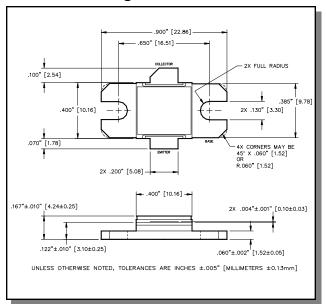
#### **Features**

- NPN silicon microwave power transistors
- Common base configuration
- Broadband Class C operation
- High efficiency inter-digitized geometry
- Diffused emitter ballasting resistors
- Gold metallization system
- Internal input and output impedance matching
- Hermetic metal/ceramic package
- RoHS compliant

## **Absolute Maximum Ratings at 25°C**

Parameter	Symbol	Rating	Units
Collector-Emitter Voltage	V <sub>CES</sub>	65	V
Emitter-Base Voltage	$V_{EBO}$	3.0	V
Collector Current (Peak)	Ic	10.7	Α
Power Dissipation @ +25°C	P <sub>TOT</sub>	580	W
Storage Temperature	T <sub>STG</sub>	-65 to +200	°C
Junction Temperature	$T_J$	200	°C

### **Outline Drawing**



## Electrical Specifications: T<sub>C</sub> = 25 ± 5°C (Room Ambient)

Parameter	Test Conditions	Frequency	Symbol	Min	Max	Units
Collector-Emitter Breakdown Voltage	I <sub>C</sub> = 40mA		$BV_CES$	65	-	V
Collector-Emitter Leakage Current	V <sub>CE</sub> = 40V		I <sub>CES</sub>	-	7.5	mA
Thermal Resistance	Vcc = 36V, Pout = 90W	F = 3.1, 3.3, 3.5 GHz	R <sub>TH(JC)</sub>	-	0.3	°C/W
Output Power	Vcc = 36V, Pout = 90W	F = 3.1, 3.3, 3.5 GHz	P <sub>IN</sub>	-	16	W
Power Gain	Vcc = 36V, Pout = 90W	F = 3.1, 3.3, 3.5 GHz	G <sub>P</sub>	7.5	-	dB
Collector Efficiency	Vcc = 36V, Pout = 90W	F = 3.1, 3.3, 3.5 GHz	ης	35	-	%
Input Return Loss	Vcc = 36V, Pout = 90W	F = 3.1, 3.3, 3.5 GHz	RL	-	-6	dB
Load Mismatch Tolerance	Vcc = 36V, Pout = 90W	F = 3.1, 3.3, 3.5 GHz	VSWR-T	-	2:1	-

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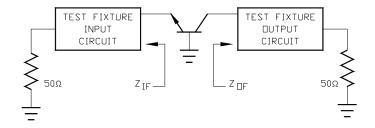


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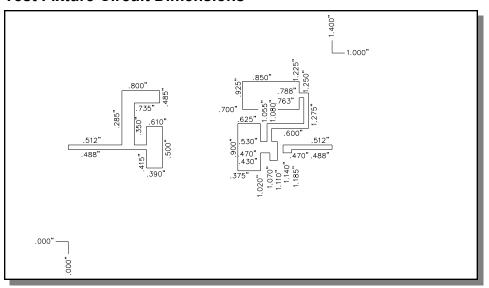
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### **RF Test Fixture Impedance**

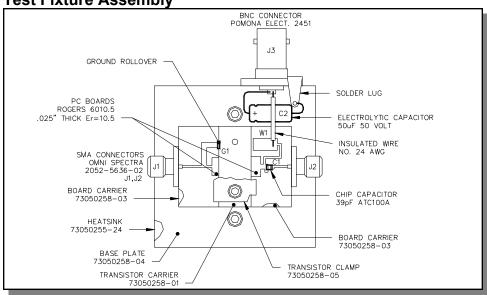
F (GHz)	Z <sub>IF</sub> (Ω)	Z <sub>OF</sub> (Ω)
3.1	8.9 - j11.2	5.2 - j11.0
3.3	8.7 - j8.6	4.2 - j8.8
3.5	8.6 - j6.0	4.7 - j7.0



#### **Test Fixture Circuit Dimensions**



**Test Fixture Assembly** 



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